BC846/BC546 series

65 V, 100 mA NPN general-purpose transistors Rev. 07 — 17 November 2009

Product data sheet

Product profile

1.1 General description

NPN general-purpose transistors in Surface Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number[1]	Package			PNP
	NXP	JEITA	JEDEC	complement
BC846	SOT23	-	TO-236AB	BC856
BC846W	SOT323	SC-70	-	BC856W
BC846T	SOT416	SC-75	-	BC856T
BC546A[2]	SOT54	SC-43A	TO-92	BC556A
BC546B[2]	SOT54	SC-43A	TO-92	BC556B

^[1] Valid for all available selection groups.

1.2 Features

- General-purpose transistors
- SMD plastic packages
- Two different gain selections

1.3 Applications

General-purpose switching and amplification

1.4 Quick reference data

Quick reference data Table 2.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	65	V
I _C	collector current		-	-	100	mA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V};$ $I_{C} = 2 \text{ mA}$	110	-	450	
	h _{FE} group A		110	180	220	
	h _{FE} group B		200	290	450	



^[2] Also available in SOT54A and SOT54 variant packages (see Section 2).

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Pinning information 2.

Pin	Description	Simplified outline Symbol
SOT23;	SOT323; SOT416	•
1	base	_
2	emitter	3
3	collector	1 2 2 sym021
SOT54		
1	emitter	
2	base	3
3	collector	001aab347 2 2 3 1 sym026
SOT54A		
1	emitter	
2	base	3
3	collector	1 2 2 3 001aab348 sym026
SOT54 v	variant	
1	emitter	
2	base	3
3	collector	001aab447 2 2 3 1 1 sym026

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Ordering information 3.

Table 4. **Ordering information**

Type number[1]	Package						
	Name	Description	Version				
BC846	-	plastic surface mounted package; 3 leads	SOT23				
BC846W	SC-70	plastic surface mounted package; 3 leads	SOT323				
BC846T	SC-75	plastic surface mounted package; 3 leads	SOT416				
BC546A[2]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
BC546B[2]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				

^[1] Valid for all available selection groups.

Marking

Product data sheet

Table 5. **Marking codes**

Type number	Marking code[1]	Type number	Marking code[1]
BC846	1D*	BC846T	1M
BC846A	1A*	BC846AT	1A
BC846B	1B*	BC846BT	1B
BC846W	1D*	BC546A	C546A
BC846AW	1A*	BC546B	C546B
BC846BW	1B*	-	-

^{[1] * = -:} made in Hong Kong

^[2] Also available in SOT54 and SOT54 variant packages (see Section 2 and Section 9).

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

Limiting values 5.

Table 6. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0 , ,	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	80	V
V_{CEO}	collector-emitter voltage	open base	-	65	V
V_{EBO}	emitter-base voltage	open collector	-	6	V
I _C	collector current		-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
I _{BM}	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u>		
	SOT23		-	250	mW
	SOT323		-	200	mW
	SOT416		-	150	mW
	SOT54		-	500	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard

Thermal characteristics

Product data sheet

Thermal characteristics Table 7.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
· -ui(j-a)	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	SOT23		-	-	500	K/W
	SOT323		-	-	625	K/W
	SOT416		-	-	833	K/W
	SOT54		-	-	250	K/W

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^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 8. Characteristics

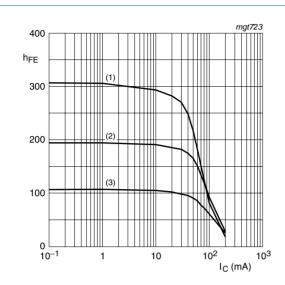
 $T_{amb} = 25 \, ^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$		-	-	15	nΑ
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$		-	-	5	μА
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{E} = 0 \text{ A}$		-	-	100	nA
h _{FE}	DC current gain						
	h _{FE} group A	$V_{CE} = 5 \text{ V}; I_{C} = 10 \mu\text{A}$		-	180	-	
	h _{FE} group B	$V_{CE} = 5 \text{ V}; I_{C} = 10 \mu\text{A}$		-	290	-	
	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$		110	-	450	
	h _{FE} group A	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$		110	180	220	
	h _{FE} group B	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$		200	290	450	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$		-	90	200	mV
		$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[1]	-	200	400	mV
V _{BEsat}	base-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	[2]	-	760	-	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[2]	-	900	-	mV
V_{BE}	base-emitter voltage	$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	580	660	700	mV
		$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	-	-	770	mV
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz		100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	2	3	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_C = i_c = 0 \text{ A};$ f = 1 MHz		-	11	-	pF
NF	noise figure	$I_C = 200 \mu A; V_{CE} = 5 V;$ $R_S = 2 k\Omega; f = 1 kHz;$ B = 200 Hz		-	2	10	dB

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

^[2] V_{BEsat} decreases by approximately 1.7 mV/K with increasing temperature.

^[3] V_{BE} decreases by approximately 2 mV/K with increasing temperature.



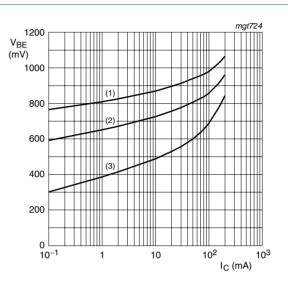
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig 1. Selection A: DC current gain as a function of collector current; typical values



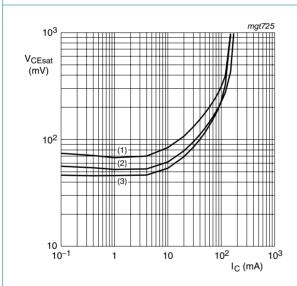
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 2. Selection A: Base-emitter voltage as a function of collector current; typical values



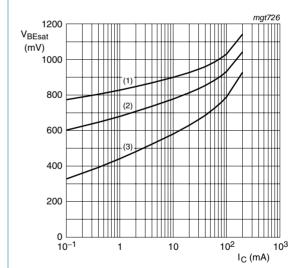
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig 3. Selection A: Collector-emitter saturation voltage as a function of collector current; typical values



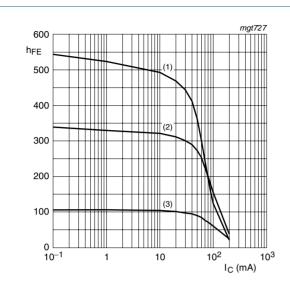
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 4. Selection A: Base-emitter saturation voltage as a function of collector current; typical values



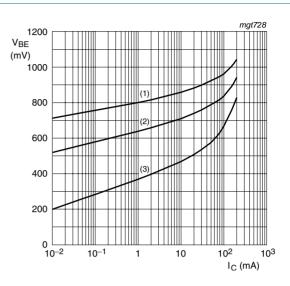
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig 5. Selection B: DC current gain as a function of collector current; typical values



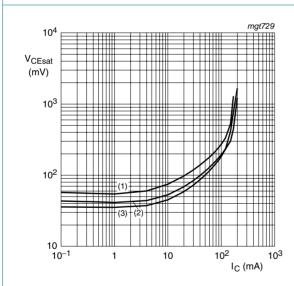
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 6. Selection B: Base-emitter voltage as a function of collector current; typical values



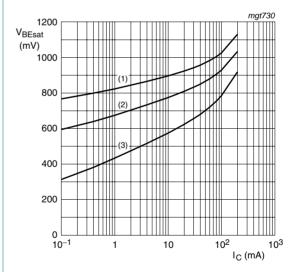
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig 7. Selection B: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

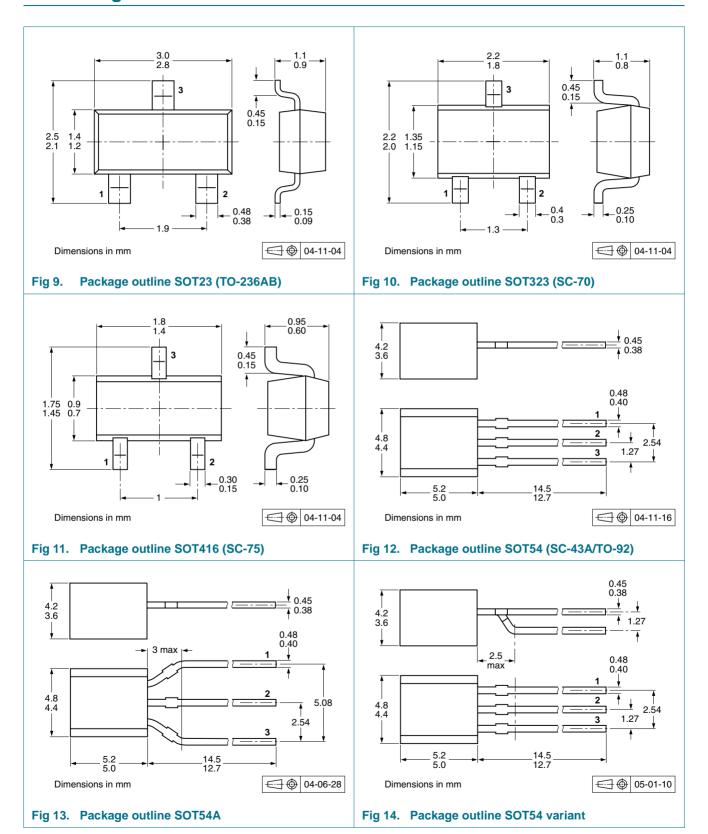
(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 8. Selection B: Base-emitter saturation voltage as a function of collector current; typical values

8. Package outline



9. Packing information

Table 9. Packing methods

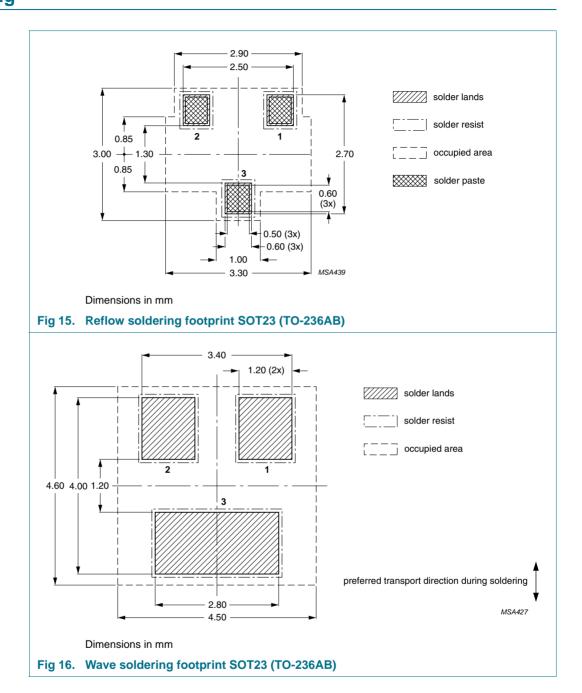
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

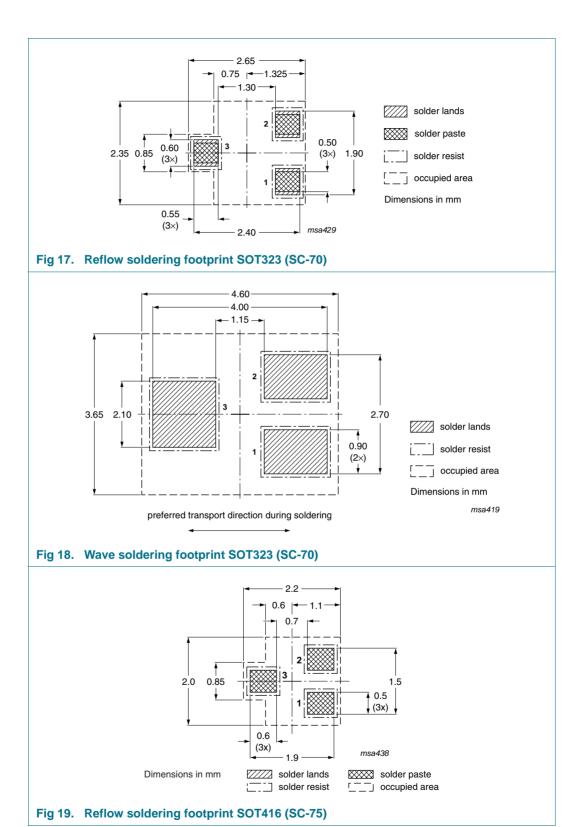
Type number[2]	Package	Description		g quanti	antity	
			3000	5000	10000	
BC846	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
BC846W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	
BC846T	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
BC546A	SOT54	bulk, straight leads	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-116	
		tape ammopack, wide pitch	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-112	-	
BC546B	SOT54	bulk, straight leads	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-116	
		tape ammopack, wide pitch	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-112	-	

^[1] For further information and the availability of packing methods, see Section 13.

^[2] Valid for all available selection groups.

10. Soldering





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11. Revision history

Table 10. Revision history

Product data sheet

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC846_BC546_SER_7	20091117	Product data sheet	-	BC846_BC546_SER_6
Modifications:		t was changed to reflect the egal definitions and disclair		
	 Table 3 "Pinnin 	g": updated		
	 Figure 17 "Refl 	ow soldering footprint SOT	323 (SC-70)": update	d
	 Figure 18 "Way 	e soldering footprint SOT3	23 (SC-70)": updated	
	 Figure 19 "Refl 	ow soldering footprint SOT	416 (SC-75)": update	d
BC846_BC546_SER_6	20060207	Product data sheet	-	BC846_BC847_ BC848_5 BC846T_847T_ SERIES_3 BC846W_BC847W_ BC848W_4 BC546_547_4
BC846_BC847_BC848_5	20040206	Product specification	-	BC846_BC847_ BC848_4
BC846T_847T_SERIES_ 3	20001115	Product specification	-	BC846T_847T_2
BC846W_BC847W_ BC848W_4	20020204	Product specification	-	BC846W_847W_3
BC546_547_4	20041125	Product specification	-	BC546_547_3

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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